TOSHIBA Photocoupler IRED + Photo IC

TLP701

Industrial inverters
Inverter for air conditioners
IGBT/Power MOS FET gate drive

TLP701 consists of an infrared emitting diode and an integrated photodetector.

This unit is 6-lead SDIP package. The TLP701 is 50% smaller than the 8-pin DIP and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring safety standard certification.

The TLP701 is suitable for gate driving circuits for IGBTs or power MOSFETs. In particular, the TLP701 is capable of "direct" gate driving of low-power IGBTs.

• Peak output current : ±0.6 A (max)

Guaranteed performance over temperature : -40 to 100°C

Supply current : 2 mA (max)Power supply voltage : 10 to 30 V

Threshold input current : I_{FLH} = 5 mA (max)

Switching time (t_{pLH} / t_{pHL}) : 700 ns (max)
 Common mode transient immunity : ±10 kV/μs (min)
 Isolation voltage : 5000 Vrms (min)

· Construction mechanical rating

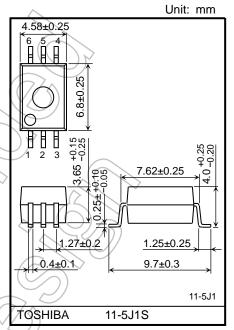
	7.62-mm pitch standard type	10.16-mm pitch TLPXXXF type
Creepage Distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation Thickness	0.4 mm (min)	0.4 mm (min)

- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
 File No.E67349
- VDE-approved: EN 60747-5-5, EN 62368-1 (Note 1)

Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

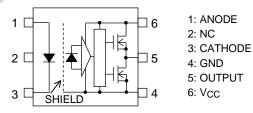
Truth Table

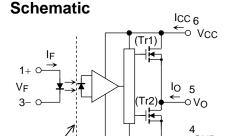
Input	ED	Tin	Tr2	Output
H	ON	ON	OFF	Н
L	OFF	OFF	ON	L



Weight: 0.26 g (typ.)

Pin Configuration (Top View)





A 0.1- μF bypass capacitor must be connected between pins 6 and 4.

Start of commercial production 2004-04

Absolute Maximum Ratings (Ta = 25 °C)

	Characteristics		Symbol	Rating	Unit
	Forward current		lF	20	mA
	Forward current derating (Ta ≥ 85°C)		ΔΙϝ/ΔΤα	-0.54	mA/°C
	Pulse transient forward current	(Note 1)	IFP	1	A
LED	Reverse voltage		V _R	5	V
	Input power dissipation		PD	40	mW
	Input power dissipation derating (Ta \geq 85	°C)	ΔΡ _D /ΔΤα	-1.0	mW/°C
	Junction temperature		Tj	125	(√. c)
	"H" peak output current	(Note 2)	IOPH	-0.6	A
	"L" peak output current	(Note 2)	I _{OPL}	0.6) A
ا ا	Output voltage		Vo	35	V
Detector	Supply voltage		Vcc	35	V
۵	Output power dissipation		PO (400	mW
	Output power dissipation derating (Ta ≥ 8	35°C)	ΔΡ ₀ /ΔΤα	1.0	mW/°C
	Junction temperature		Ţi	125	°C
Ope	rating frequency	(Note 3)	\(\frac{1}{2}\)	25	kHz
Ope	Operating temperature range		Topr	-40 to 100	(c)
Storage temperature range		Tstg	-55 to 125	∕\°C	
Lead soldering temperature (10 s) (Note 4)		Tsol	260	∕∕°c	
Isola	tion voltage (AC, 60 s, R.H. ≤ 60 %)	(Note 5)	BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: A ceramic capacitor (0.1 µF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

Note 1: Pulse width P_W ≤ 1 μs, 300 pps

Note 2: Exponential waveform pulse width $P_W \le 2 \mu s$, $f \le 15 \text{ kHz}$

Note 3: Exponential waveform $I_{OPH} \le -0.3 \text{ A} (\le 2 \mu \text{s}), I_{OPL} \le +0.3 \text{ A} (\le 2 \mu \text{s}), Ta = 100 °C$

Note 4: For the effective lead soldering area

Note 5: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.

Recommended Operating Conditions

Characteristics	52	Symbol	Min	Тур.	Max	Unit
Input current, ON	(Note 6)	IF (ON)	7.5	_	10	mA
Input voltage, OFF		VF (OFF)	0	_	0.8	V
Supply voltage		Vcc	10	1	30	٧
Peak output current		IOPH / IOPL	_	_	± 0.2	Α
Operating temperature		Topr	-40	_	100	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 6: Input signal rise time (fall time) $< 0.5~\mu s.$

Electrical Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

Characteristics		Symbol	Test Circuit	Test Condition		Min	Тур.*	Max	Unit
Forward voltage		VF	_	I _F = 5 mA, Ta = 25	5 °C	_	1.55	1.70	V
Temperature coefficient of voltage	forward	ΔV _F /ΔTa	_	I _F = 5 mA	<	_	-2.0	_	mV/°C
Input reverse current		IR	_	V _R = 5 V, Ta = 25	°C		_	10	μА
Input capacitance		Ст	_	V =0 V, f = 1 MHz	, Ta = 25 °C	((-))	45	_	pF
	"H" Level	IOPH1	1	V _{CC} = 15 V	V6-5 = 4 V		-0.38	-0.2	
Output current (Note 7)	n Levei	I _{OPH2}	ı	$I_F = 5 \text{ mA}$	V6-5 = 10 V	()	-0.60	-0.4	- A
	"L" Level	I _{OPL1}	2	V _{CC} = 15 V I _F = 0 mA	V5-4 = 2 V	0.2	0.36	_	
		I _{OPL2}			V5-4 = 10 V	0.4	0.62	_	
Output valtage	"H" Level	Voн	3	V _{CC} = 10 V	10 = -100 mA, (F = 5 mA	6.0	8.5	-	V
Output voltage	"L" Level	V _{OL}	4		I _O = 100 mA, V _F = 0.8 V	-	0.4	1.0	V
Cupply ourrent	"H" Level	Іссн	5	Vcc = 10 to 30 V	JF = 10 mA 🔷	, (()	1.4	2.0	A
Supply current	"L" Level	ICCL	6	Vo = Open	I _F = 0 mA	1	1.3	2.0	mA
Threshold input current	$L \rightarrow H$	I _{FLH}	_	V _{CC} = 15 V, V _O > 1 V			2.5	5	mA
Threshold input voltage	$H \rightarrow L$	V _{FHL}	_	V _{CC} = 15 V, V _O < 1 V		0.8	_	_	V
Supply voltage		Vcc	((- ((7/\$	10	_	30	V

^{(*):} All typical values are at Ta = 25 $^{\circ}$ C

Note: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design. It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

Note 7: Duration of IO time ≤ 50 µs, 1 pulse

Isolation Characteristics (Ta = 25 °C)

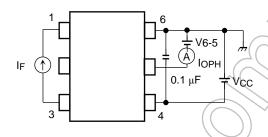
Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0 V , f = 1 MHz	(Note 5)	_	1.0	_	pF
Isolation resistance	Rs	R.H. ≤ 60 %, V _S = 500 V	(Note 5)	1×10 ¹²	10 ¹⁴	ı	Ω
Isolation voltage	BVs	AC, 60 s	(Note 5)	5000	-	-	Vrms

Switching Characteristics (Ta = −40 to 100 °C, unless otherwise specified)

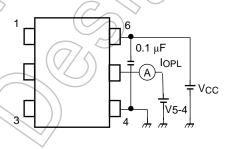
Characteristics		Symbol	Test Circuit	Test Condition		Min	Тур.*	Max	Unit
Dropogation dolay time	L → H tpLH	$I_F = 0 \rightarrow 5 \text{ mA}$	100	_	700				
Propagation delay time H → L	tpHL	7 F	$V_{CC} = 30 \text{ V}$ $R_g = 47 \Omega$ $C_g = 3 \text{ nF}$	$I_F = 5 \rightarrow 0 \text{ mA}$	100	_	700		
Output rise time (10-90 %)				tr	$I_F = 0 \rightarrow 5 \text{ mA}$	7	50	_	ns
Output fall time (90-10 %)				tf	$I_F = 5 \rightarrow 0 \text{ mA}$	(50	_	
Switching time dispersion between ON and OFF		tpHL- tpLH			IF = 0 ⇔ 5 mA	775) _	500	
Common mode transient i at HIGH level output	mmunity	СМн	۰	V _{CM} = 1000 Vp-p	IF = 5 mA VO (min) = 26 V	-10000	_	_	\// ₁ .0
Common mode transient i at LOW level output	mmunity	CML	8	8 V _{CC} = 30 V Ta = 25 °C	IF = 0 mA VO (max) = 1 V	10000	_	_	V/μs

(*): All typical values are at Ta = 25 °C.

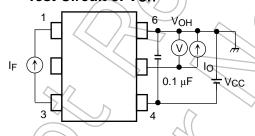




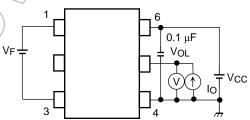
Test Circuit 2: IOPL



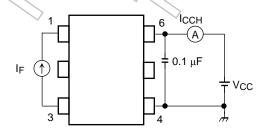
Test Circuit 3: VoH



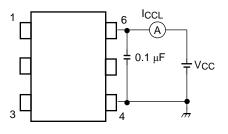
Test Circuit 4: Vol



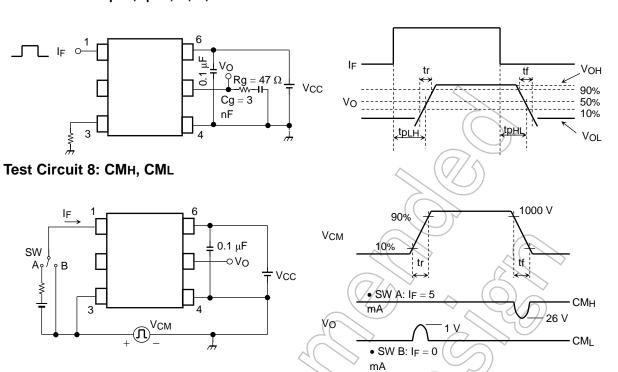
Test Circuit 5: ICCH



Test Circuit 6: IccL



Test Circuit 7: tpLH, tpHL, tr, tf, PDD



 $CMH = -\frac{800 \text{ V}}{\text{tf (}\mu\text{s)}}$

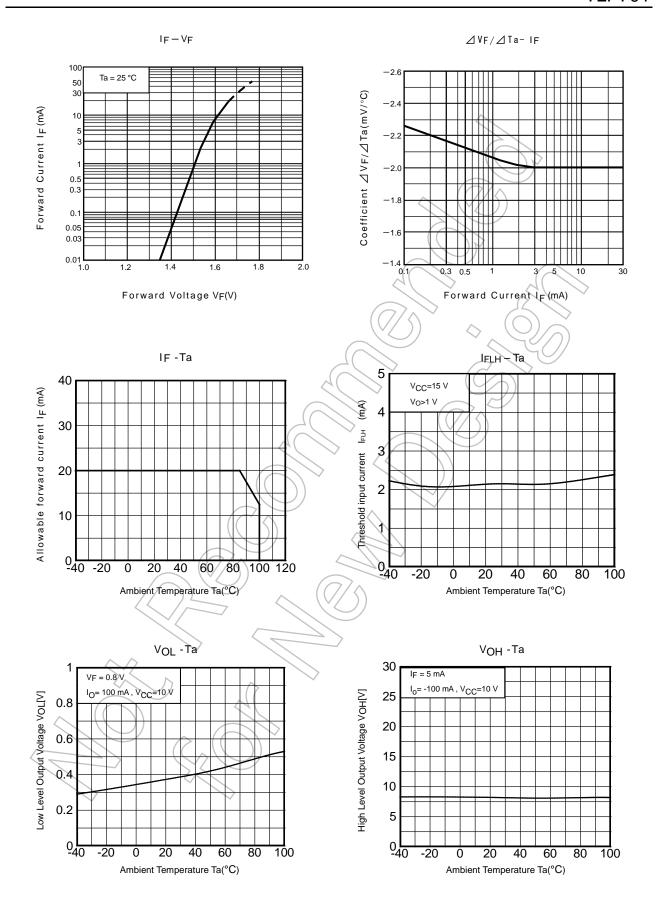
800 V

tr (μs)

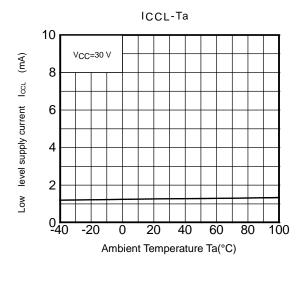
CML

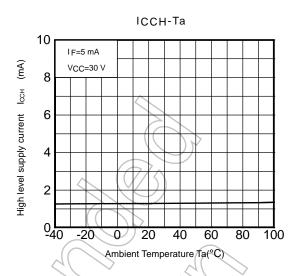
CML (CMH) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the LOW (HIGH) state.

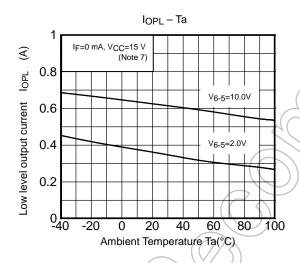


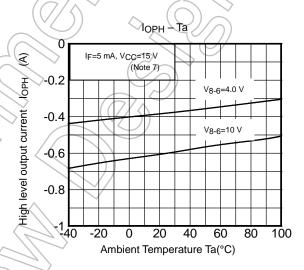


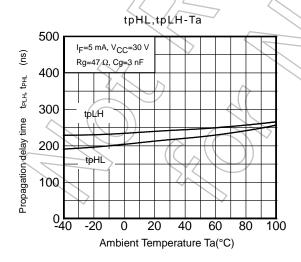
NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.











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